ECE 331 Spring 2013

Homework 8

Due Mon March 18 at the beginning of class.

1. Explain (in words/sentences) what the following program segment does. Be sure to state what values are stored in accA and accB when at the end of the program segment.

| | LDAB | #\$AF | | |
|-----|-------|--------|------|-----|
| | STAB | \$64F0 | | |
| AGN | DEC | \$64F0 | | |
| | BRCLR | \$64F0 | \$0F | STP |
| | BRA | AGN | | |
| STP | LDAA | \$64F0 | | |

- 2. Types of memory:
 - a) What does it mean if memory is non-volatile?
 - b) What is the key difference between RAM and ROM?
 - c) What is the key difference between ROM and EEPROM?
 - d) What is the key difference between RAM and EEPROM?
 - e) Comparing SRAM and DRAM, describe one advantage of each relative to the other.
- 3. A memory system contains 32 data lines and 20 address lines. Specify:
 - a) the number of addressable memory locations
 - b) the width of the memory
 - c) the length of the memory
 - d) the size of the memory in bytes
 - e) the size of the memory in bits
- 4. Following examples from lecture, construct and diagram a memory interface using the HCS12 MCU and external 1k-byte x 8-bit RAM chips (like the figure below). Show how an external 4k X 16 RAM could be generated. Show all the necessary address, data, and control signals.

